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The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact the sales office, which is responsible for you. Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact the sales office, which is responsible for you. Should you intend to use the product in aviation, in health or live endangering or life support applications, please notify. For any such application we urgently recommend to perform joint risk and guality assessments:

- the conclusion of quality agreements;
- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

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DCG100X1200NA

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SiC Diod	е			Rating	s	
Symbol	Definitions	Conditions	min.	typ.	max.	
V _{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}C$			1200	V
V _{RRM}	max. repetitive reverse blocking voltage	$T_{vJ} = 25^{\circ}C$			1200	V
I _R	reverse current	$V_{R} = V_{RRM} \qquad \qquad T_{VJ} = 25^{\circ}C$ $T_{VJ} = 175^{\circ}C$		100 300	500 1000	μA μA
V _F	forward voltage	$I_F = 25 A$ $T_{VJ} = 25^{\circ}C$ $I_F = 50 A$		1.25 1.6	1.8	V V
		$I_F = 25 \text{ A}$ $T_{VJ} = 175^{\circ}\text{C}$ $I_F = 50 \text{ A}$		1.55 2.25	2.7	V V
I _{FAV}	average forward current	$ \begin{array}{ccc} T_c = & 80^\circ C \\ T_c = & 100^\circ C \end{array} \end{array} \Big) \begin{array}{c} \mbox{rectangular, } d = 0.5 \\ T_{VJ} = & 175^\circ C \end{array} $			49 43	A A
_{F25} _{F80} _{F100}	forward current	$T_{c} = 25^{\circ}C$ $T_{c} = 80^{\circ}C$ $T_{c} = 100^{\circ}C$			86 66 59	A A A
I _{FSM}	max forward surge current	t = 10 ms,half sine (50 Hz) $t_P = 10 \ \mu s$, pulse $T_{VJ} = 25^{\circ}C$ $V_R = 0V$			250	A A
Q _c	total capacitive charge	V _R = 800 V, I _F = 50A dl/dt = 200 A/μs		250		nC
С	total capacitance	$V_{R} = 0 V$ $V_{R} = 400 V$ $V_{R} = 800 V$ $T_{VJ} = 25^{\circ}C, f = 1 MHz$		3380 230 173		pF pF pF
$f R_{thJC} \ R_{thJH}$	thermal resistance junction to case thermal resistance junction to heatsink	with heatsink compound; IXYS test setup		0.66	0.51	K/W K/W

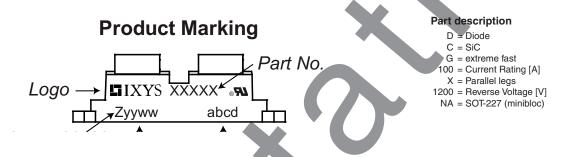
1



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Package	Outlines SOT-227B (minibloc)			Ratings			
Symbol	Definitions	Conditions		min.	typ.	max.	Unit
I _{RMS}	RMS current	per terminal				100	A
T _{stg} T _{op} T _{VJ}	storage temperature operation temperature virtual junction temperature			-40 -40 -40		150 150 175	0° 0° 0°
Weight					30		g
M _D	mounting torque ¹⁾	screws to heats terminal connec				1.5 1.3	Nm Nm
d _{Spp} d _{Spb}	creepage distance on surface		terminal to terminal terminal to backside	10.5 8.5			mm mm
d _{App} d _{Apb}	striking distance through air		terminal to terminal terminal to backside	3.2 6.8			mm mm
VISOL	isolation voltage	t = 1 second t = 1 minute	50 / 60 Hz, RMS; $I_{ISOL} \leq 1 \text{ mA}$	3000 2500			V V
C _P	coupling capacity per switch	between shorted te lization	erminals of diodes and back side metal-				pF
	ormation see application note IXAN00 com/TechnicalSupport/appnotes.aspx		Mounting, Soldering, Cooling)				



Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Ordering Code
Standard	DCG100X1200NA	DCG100X1200NA	Tube	10	521465

Equivale	ent Circuits for Simulatio	n *on die level		
	- R ₀ -	T _{vJ} = 125°C	T _{vJ} = 175°C	
V _{0 max}	threshold voltage	0.80	0.73	V
R _{0 max}	slope resistance *	28.4	35.2	mΩ

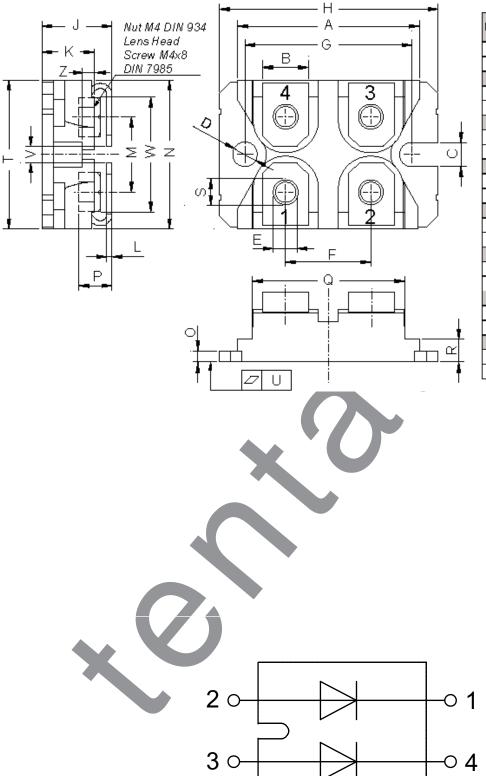
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Outlines SOT-227B (minibloc)



Dim.	Millimeter		Inches		
Dim.	min	max	min	max	
Α	31.50	31.88	1.240	1.255	
В	7.80	8.20	0.307	0.323	
С	4.09	4.29	0.161	0.169	
D	4.09	4.29	0.161	0.169	
E	4.09	4.29	0.161	0.169	
F	14.91	15.11	0.587	0.595	
G	30.12	30.30	1.186	1.193	
Н	37.80	38.23	1.488	1.505	
J	11.68	12.22	0.460	0.481	
К	8.92	9.60	0.351	0.378	
L	0.74	0.84	0.029	0.033	
M	12.50	13.10	0.492	0.516	
N	25.15	25.42	0.990	1.001	
0	1.95	2.13	0.077	0.084	
Ρ	4.95	6.20	0.195	0.244	
Q	26.54	26.90	1.045	1.059	
R	3.94	4.42	0.155	0.167	
S	4.55	4.85	0.179	0.191	
Т	24.59	25.25	0.968	0.994	
U	-0.05	0.10	-0.002	0.004	
V	3.20	5.50	0.126	0.217	
W	19.81	21.08	0.780	0.830	
Ζ	2.50	2.70	0.098	0.106	

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